

±16.5kV ESD Protected, +125°C, 1.8V to 3.6V, Low Power, SOT-23, RS-485/RS-422 Transmitters

ISL32613E, ISL32614E

The Intersil <code>ISL32613E</code> and <code>ISL32614E</code> are ± 16.5 kV HBM ESD Protected (7kV IEC61000 contact), 1.8V powered, single transmitters for differential communication. These drivers have very low bus currents ($\pm 40\mu A$), so they present less than a "1/8 unit load" to the bus. This allows more than 256 transmitters on the network, without violating the RS-485 specification's 32 unit load maximum and without using repeaters.

Hot Plug circuitry ensures that the Tx outputs remain in a high impedance state while the power supply stabilizes.

Both ICs utilize slew rate limited drivers, which reduce EMI and minimize reflections from improperly terminated transmission lines or unterminated stubs in multidrop and multipoint applications. The ISL32613E is more slew rate limited for data rates up to 128kbps, while the less limited ISL32614E is useful for data rates up to 256kbps.

For companion low power single RS-485 receivers, please see the ISL32610E datasheet.

Features

•	Wide supply voltage range 1.8V to 3.6V
•	Low quiescent supply current 80µA (max)
	- Very low shutdown supply current 2 μ A (max)
•	High ESD protection on RS-485 outputs ±16.5kV HBM
	- Class 3 ESD level on all other pins>8kV HBM

- Specified for +125°C or full military temperature range
- Hot Plug Tx outputs remain three-state during power-up
- Low Tx leakage allows >256 devices on the bus
- · Slew rate limited for data rates up to 256kbps
- Current limiting and thermal shutdown for driver overload protection
- . 5V tolerant logic inputs
- · Pb-Free (RoHS Compliant)

Applications

- · Industrial/process control networks
- · Space-constrained systems
- Factory automation
- · Building environmental control/lighting systems

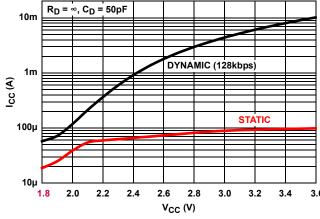


FIGURE 1. ISL32613E WITH V $_{CC}$ = 1.8V REDUCES OPERATING I $_{CC}$ BY A FACTOR OF 177 COMPARED WITH I $_{CC}$ AT V $_{CC}$ = 3.6V

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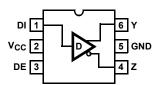
Truth Table

TRANSMITTING						
INP	UTS	OUTI	PUTS			
DE (Note 9)	DI	Z	Y			
1	1	0	1			
1	0	1	0			
0	Х	High-Z *	High-Z *			

NOTE: *Shutdown Mode

Pin Configuration

ISL32613E, ISL32614E (6 LD SOT-23) TOP VIEW



Pin Descriptions

PIN#	PIN NAME	FUNCTION
1	DI	Driver input. A low on DI forces output Y low and output Z high. Similarly, a high on DI forces output Y high and output Z low.
2	V _{CC}	System power supply input (1.8V to 3.6V).
3	DE	Driver output enable. The driver outputs, Y and Z, are enabled by bringing DE high, and are high impedance when DE is low. If the driver enable function is not needed, connect DE to V_{CC} through a $1k\Omega$ to $2k\Omega$ resistor.
4	Z	±16.5kV HBM, ±7kV IEC61000 (contact method) ESD Protected inverting differential transmitter output.
5	GND	Ground connection
6	Y	±16.5kV HBM, ±7kV IEC61000 (contact method) ESD Protected noninverting differential transmitter output.

TABLE 1. SUMMARY OF FEATURES AT $V_{CC} = 1.8V$

PART NUMBER	FUNCTION	DATA RATE (kbps)	SLEW-RATE LIMITED?	HOT PLUG?	TX ENABLE? (Note 9)	MAXIMUM QUIESCENT I _{CC} (μA)	LOW POWER SHUTDOWN?	PIN COUNT
ISL32613E	1 Tx	128	Yes	Yes	Yes	80	Yes	6 Ld SOT
ISL32614E	1 Tx	256	Yes	Yes	Yes	80	Yes	6 Ld SOT

Ordering Information

PART NUMBER (Notes 1, 2)	PART MARKING (Note 4)	TEMP RANGE (°C)	PACKAGE (RoHS Compliant)	PKG. DWG. #
ISL32613EFHZ-T	613F	-40 to +125	6 Ld SOT-23	P6.064
ISL32613EFHZ-T7A	613F	-40 to +125	6 Ld SOT-23	P6.064
ISL32614EFHZ-T	614F	-40 to +125	6 Ld SOT-23	P6.064
ISL32614EFHZ-T7A	614F	-40 to +125	6 Ld SOT-23	P6.064

NOTES:

- 1. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- 2. Please refer to TB347 for details on reel specifications.
- 3. For Moisture Sensitivity Level (MSL), please see device information page for ISL32614E. For more information on MSL please see techbrief IB363.
- 4. SOT-23 "PART MARKING" is branded on the bottom side.

Typical Operating Circuits

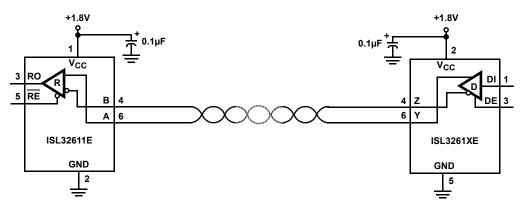


FIGURE 2. NETWORK WITH ENABLES

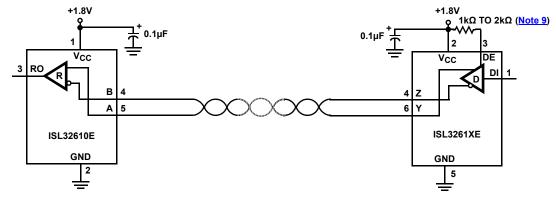


FIGURE 3. NETWORK WITHOUT ENABLES

ISL32613E, ISL32614E

Absolute Maximum Ratings

V _{CC} to GND0.3V to 7V
Input Voltages
DI, DE0.3V to 7V
Output Voltages
Y, Z (V _{CC} = 0V or ≥ 2.7V)8V to +13V
Y, Z (V _{CC} = 1.8V, Output Enabled))8V to +3V
Y, Z (V _{CC} = 1.8V, Output Disabled))8V to +8V
Short Circuit Duration
Y, Z Indefinite
ESD Rating see "Electrical Specifications"
Latch-up (per JESD78, Level 2, Class A)+125°C

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W	/) θ _{JC} (°C/W)
6 Ld SOT-23 Package (Notes 5, 6)	. 177	95
Maximum Junction Temperature (Plastic Page	ckage)	+150°C
Maximum Storage Temperature Range		-65°C to +150°C
Pb-free Reflow Profile		see TB493

Recommended Operating Conditions

Supply Voltage Range	1.8V to 3.3V
Common Mode Range; V _{CC} = 1.8V	±2V
V _{CC} ≥ 2.7V	7V to +12V
Temperature Range	
(F Suffix)	-40°C to +125°C
Differential Load (R _D); V _{CC} = 1.8V	≥10kΩ
V _{CC} ≥ 2.7V	≥60Ω

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES

- 5. θ_{IA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- 6. For $\theta_{\mbox{\scriptsize JC}},$ the "case temp" location is taken at the package top center.

Electrical Specifications $V_{CC} = 1.8V$; typicals are at $T_A = +25$ °C; unless otherwise specified. **Boldface limits apply across the operating** temperature range. (Note 7)

PARAMETER	SYMBOL	TEST CONDITIONS		TEMP (°C)	MIN (Note 10)	TYP	MAX (Note 10)	UNIT
DC CHARACTERISTICS	1	1			ı		'	
Driver Differential V _{OUT}	V _{OD}	$R_L = 100\Omega (Figure 4)$	V _{CC} = 1.8V	Full	0.8	0.92	-	٧
			V _{CC} ≥ 3.15V	Full	2	-	-	٧
		$R_L = 54\Omega (\frac{\text{Figure 4}}{}), V_{CC} \ge$	3V	Full	1.5	-	-	٧
		No Load		Full	1.1	1.45	V _{CC}	٧
Change in Magnitude of Driver Differential V _{OUT} for Complementary Output States	ΔV _{OD}	R _L = 100Ω (<u>Figure 4</u>)		Full	-	0.01	0.2	V
Driver Common Mode V _{OUT}	v _{oc}	$R_L = 100\Omega (Figure 4)$		Full	-	1.1	1.4	٧
Change in Magnitude of Driver Common Mode V _{OUT} for Complementary Output States	ΔV _{OC}	R _L = 100Ω (<u>Figure 4</u>)		Full	-	0.01	0.2	V
Logic Input High Voltage (DI, DE)	V _{IH}	V _{CC} = 1.8V		Full	1.26	-	-	٧
		2.7V ≤ V _{CC} ≤ 3.6V		Full	2.2	-	-	٧
Logic Input Low Voltage (DI, DE)	V _{IL}	V _{CC} = 1.8V		Full	-		0.4	٧
		2.7V ≤ V _{CC} ≤ 3.6V		Full	-		0.8	٧
Logic Input Current	I _{IN}	DI = DE = OV or V _{CC} (Note S	<u>2</u>)	Full	-2		2	μΑ
Output Leakage Current	loz	DE = OV,	$V_0 = 7V$ at $V_{CC} = 1.8V$	Full	-	0.1	30	μΑ
(Y, Z, <u>Note 9</u>)		V _{CC} = 0V or 1.8V, or 3.6V	V _O = 12V at V _{CC} = 3.6V	Full	-	0.1	40	μΑ
			V _O = -7V	Full	-40	-8	-	μΑ
Driver Short-circuit Current,	los	V _{CC} = 1.8V, DE = V _{CC} , -2V ≤	S V ₀ ≤ 2V	Full	-		±250	mA
V ₀ = High or Low (<u>Note 8</u>)		V _{CC} ≥ 2.7V, DE = V _{CC} , -7V ≤	S V ₀ ≤ 12V	Full	-	±150	-	mA

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ISL32613E, ISL32614E

Electrical Specifications $V_{CC} = 1.8V$; typicals are at $T_A = +25$ °C; unless otherwise specified. **Boldface limits apply across the operating** temperature range. (Note 7) (Continued)

PARAMETER	SYMBOL	TEST CO	NDITIONS	TEMP (°C)	MIN (<u>Note 10</u>)	TYP	MAX (Note 10)	UNIT
SUPPLY CURRENT								
No-load Supply Current	I _{CC}	$DE = V_{CC} = 1.8V$, $DI = 0V$ or V_{CC}		Full	-	20	80	μΑ
		$DE = V_{CC}, 2.7V \le V_{CC} \le 3.0$	6V, DI = OV or V _{CC}	Full	-	100	150	μΑ
Shutdown Supply Current	I _{SHDN}	1.8V ≤ V _{CC} ≤ 3.6V, DE = 0	V, DI = OV or V _{CC}	Full	-	0.01	2	μΑ
ESD PERFORMANCE					I			
RS-485 Pins (Y, Z)		Human Body Model, from	uman Body Model, from bus pins to GND		-	±16.5	-	kV
		IEC61000 Contact, from b	ous pins to GND	25	-	±7	-	kV
All Pins		HBM, per MIL-STD-883 Me	ethod 3015	25	-	±8	-	kV
		Machine Model		25	-	±400	-	٧
DRIVER SWITCHING CHARACTERISTI	CS (ISL32613	E, 128kbps Version)			I.		1	
Maximum Data Rate	f _{MAX}		V _{CC} = 1.8V	Full	128	-	-	kbps
			3V ≤ V _{CC} ≤ 3.6V	Full	256	-	-	kbps
Driver Differential Output Delay	t _{DD}	C _D = 50pF (<u>Figure 5</u>)	V _{CC} = 1.8V	Full	-	1700	2600	ns
			3V ≤ V _{CC} ≤ 3.6V	Full	-	1100	1500	ns
Driver Differential Output Skew	t _{DSK}	C _D = 50pF (<u>Figure 5</u>)	V _{CC} = 1.8V	Full	-	30	200	ns
			3V ≤ V _{CC} ≤ 3.6V	Full	-	2	30	ns
Driver Differential Rise or Fall Time t _R	t _R , t _F	C _D = 50pF (<u>Figure 5</u>)	V _{CC} = 1.8V	Full	-	1600	2600	ns
			3V ≤ V _{CC} ≤ 3.6V	Full	400	960	1500	ns
Driver Enable to Output High	t _{ZH}	$R_L = 500\Omega, C_L = 50pF, SV$	/ = GND (<u>Figure 6</u>)	Full	-	460	800	ns
Driver Enable to Output Low	t _{ZL}	$R_L = 500\Omega, C_L = 50pF, SV$	/ = V _{CC} (<u>Figure 6</u>)	Full	-	460	800	ns
Driver Disable from Output High	t _{HZ}	$R_L = 500\Omega, C_L = 50pF, SV$	/ = GND (<u>Figure 6</u>)	Full	-	60	250	ns
Driver Disable from Output Low	t _{LZ}	$R_L = 500\Omega, C_L = 50pF, SW$	/ = V _{CC} (<u>Figure 6</u>)	Full	-	60	250	ns
DRIVER SWITCHING CHARACTERISTI	CS (ISL32614	E, 256kbps Version)					1	
Maximum Data Rate	f _{MAX}	R _D = ∞, C _D = 50pF	V _{CC} = 1.8V	Full	256	-	-	kbps
			3V ≤ V _{CC} ≤ 3.6V	Full	500	-	-	kbps
Driver Differential Output Delay	t _{DD}	$R_D = \infty$, $C_D = 50pF$	V _{CC} = 1.8V	Full	-	700	2000	ns
		(<u>Figure 5</u>)	3V ≤ V _{CC} ≤ 3.6V	Full	-	350	500	ns
Driver Differential Output Skew	t _{DSK}	R _D = ∞, C _D = 50pF	V _{CC} = 1.8V	Full	-	30	200	ns
		(<u>Figure 5</u>)	3V ≤ V _{CC} ≤ 3.6V	Full	-	2	30	ns
Driver Differential Rise or Fall Time	t _R , t _F	R _D = ∞, C _D = 50pF	V _{CC} = 1.8V	Full	-	1700	2600	ns
		(<u>Figure 5</u>)	3V ≤ V _{CC} ≤ 3.6V	Full	200	350	800	ns
Driver Enable to Output High	t _{ZH}	$R_L = 500\Omega$, $C_L = 50pF$, $SW = GND$ (Figure 6)		Full	-	460	800	ns
Driver Enable to Output Low	t _{ZL}	$R_L = 500\Omega, C_L = 50pF, SV$	/ = V _{CC} (Figure 6)	Full	-	460	800	ns
Driver Disable from Output High	t _{HZ}	$R_L = 500\Omega, C_L = 50pF, SW$	/ = GND (<u>Figure 6</u>)	Full	-	60	250	ns
Driver Disable from Output Low	t _{LZ}	$R_L = 500\Omega$, $C_L = 50$ pF, $SW = V_{CC}$ (Figure 6)		Full	-	60	250	ns

NOTES:

- 7. All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to device ground unless otherwise specified.
- 8. Applies to peak current. See "Typical Performance Curves" on page 8 for more information.
- 9. If the Driver Enable function is not needed, connect DE to V_{CC} through a $1k\Omega$ to $2k\Omega$ resistor.
- 10. Compliance to data sheet limits is assured by one or more methods: production test, characterization and/or design.

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Test Circuits and Waveforms

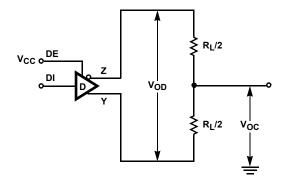
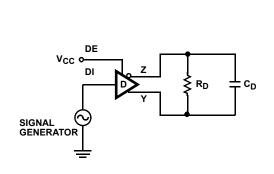
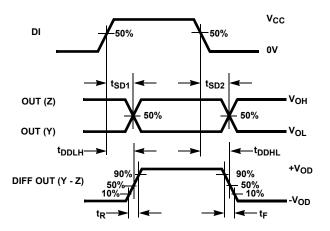


FIGURE 4. DC DRIVER TEST CIRCUITS





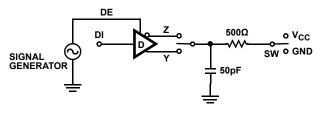
 $t_{SSK} = |t_{SD1(Y)} - t_{SD2(Y)}| OR |t_{SD1(Z)} - t_{SD2(Z)}|$ t_{DS}

tDSK = |tDDLH - tDDHL|

FIGURE 5A. TEST CIRCUIT

FIGURE 5B. MEASUREMENT POINTS

FIGURE 5. DRIVER PROPAGATION DELAY AND DIFFERENTIAL TRANSITION TIMES



PARAMETER	OUTPUT	DI	SW
t _{HZ}	Y/Z	1/0	GND
t _{LZ}	Y/Z	0/1	v _{cc}
t _{ZH}	Y/Z	1/0	GND
t _{ZL}	Y/Z	0/1	V _{CC}

OUT (Y, Z)

FIGURE 6A. TEST CIRCUIT

FIGURE 6B. MEASUREMENT POINTS

FIGURE 6. DRIVER ENABLE AND DISABLE TIMES

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Application Information

Driver Features

These transmitters are differential output devices that operate with V_{CC} as low as 1.8V, and up to 3.6V. Devices are RS-485 compliant with V_{CC} \geq 3V, but significant power savings are obtained by operating at V_{CC} = 1.8V.

The transmitter outputs are tri-statable via the active high DE input. If the Tx enable function is not needed, tie DE to V_{CC} through a $1k\Omega$ to $2k\Omega$ resistor. Outputs are slew rate limited to minimize EMI, and to reduce reflections in unterminated or improperly terminated networks.

1.8V Operation

The ISL32613E and ISL32614E operate with V $_{CC}$ as low as 1.8V. When coupled with the ISL32610E or ISL32611E 1.8V receivers, they provide a differential communication link optimized for very low power, and for slow data rates. Figures 9 and 10 illustrate the static and dynamic power savings from using these transmitters at low supply voltages. With V $_{CC}$ = 1.8V rather than 3.3V, using the ISL32613E at 128kbps reduces the operating supply current from 9.9mA to 56µA (a factor of 177).

5.5V Tolerant Logic Pins

Logic input pins (DI, DE) contain no ESD or parasitic diodes to V_{CC} , so they withstand input voltages exceeding 5.5V, regardless of the V_{CC} voltage.

Hot Plug Function

When a piece of equipment powers up, there is a period of time during which the processor or ASIC driving the RS-485 control line (DE) is unable to ensure that the RS-485 Tx outputs are kept disabled. If the equipment is connected to the bus, a driver activating prematurely during power-up may crash the bus. To avoid this scenario, these transmitters incorporate a "Hot Plug" function. During power-up, circuitry monitoring V_{CC} ensures that the Tx outputs remain disabled for a period of time, regardless of the state of DE. This gives the processor/ASIC a chance to stabilize and drive the control lines to the proper states.

ESD Protection

All pins on these devices include class 3 (8kV) Human Body Model (HBM) ESD protection structures, but the driver outputs incorporate advanced structures that allow them to survive ESD events in excess of ±16.5kV HBM and ±7kV to the IEC61000 contact test method. The RS-485 pins are particularly vulnerable to ESD damage because they typically connect to an exposed port on the exterior of the finished product. Simply touching the port pins, or connecting a cable, can cause an ESD event that might destroy unprotected ICs. These new ESD structures protect the device whether it is powered up or not, and without degrading the common mode range. This built-in ESD protection eliminates the need for board-level protection structures (e.g., transient suppression diodes) and the associated, undesirable capacitive load they present.

Driver Overload Protection

The driver output stages incorporate short-circuit, current-limiting circuitry, which ensures that the output current never exceeds the RS-485 specification over a $\pm 2V$ (-7V to $\pm 12V$ for $V_{CC} \ge 2.7V$) common mode voltage range.

In the event of a major short-circuit condition, the device also includes a thermal shutdown feature that disables the drivers whenever the die temperature becomes excessive. This eliminates power dissipation, allowing the die to cool. The drivers automatically reenable after the die temperature drops by about +20°C. If the condition persists, the thermal shutdown/reenable cycle repeats until the fault is cleared.

Low Power Shutdown Mode

This BiCMOS transmitter uses a fraction of the power required by its bipolar counterparts, but it also includes a shutdown feature that reduces the already low quiescent I_{CC} to a 10nA trickle. This device enters shutdown whenever the driver disables (DE = GND).

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Typical Performance Curves $v_{CC} = 1.8V$, $T_A = +25$ °C; unless otherwise specified.

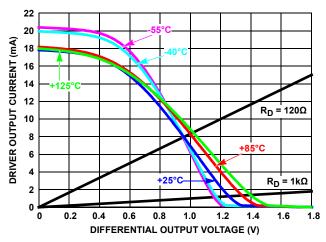


FIGURE 7. DRIVER OUTPUT CURRENT vs DIFFERENTIAL OUTPUT **VOLTAGE**

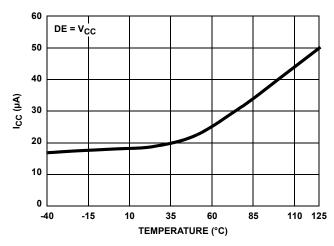


FIGURE 8. STATIC SUPPLY CURRENT vs TEMPERATURE

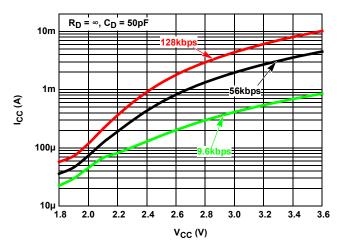


FIGURE 9. ISL32613E DYNAMIC SUPPLY CURRENT vs SUPPLY **VOLTAGE AT DIFFERENT DATA RATES**

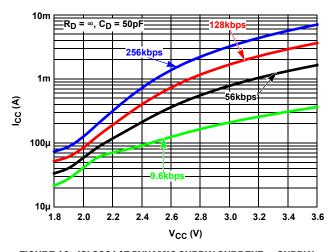


FIGURE 10. ISL32614E DYNAMIC SUPPLY CURRENT vs SUPPLY **VOLTAGE AT DIFFERENT DATA RATES**

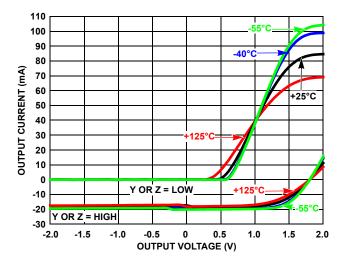


FIGURE 11. DRIVER OUTPUT CURRENT vs SHORT-CIRCUIT VOLTAGE

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Typical Performance Curves $v_{CC} = 1.8V$, $T_A = +25$ °C; unless otherwise specified. (Continued)

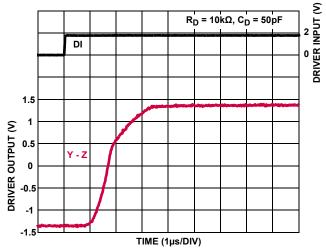


FIGURE 12. ISL32613E DRIVER WAVEFORMS, LOW-TO-HIGH

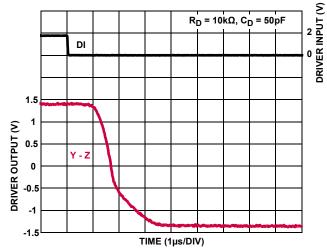


FIGURE 13. ISL32614E DRIVER WAVEFORMS, HIGH-TO-LOW

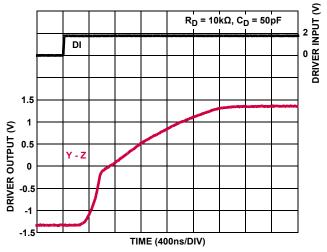


FIGURE 14. ISL32614E DRIVER WAVEFORMS, LOW-TO-HIGH

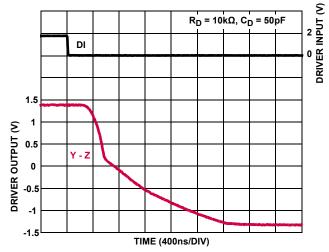


FIGURE 15. ISL32614E DRIVER WAVEFORMS, HIGH-TO-LOW

Die Characteristics

SUBSTRATE POTENTIAL (POWERED UP):

GND

PROCESS:

Si Gate BiCMOS

ISL32613E, ISL32614E

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

DATE	REVISION	CHANGE
July 27, 2015	FN7906.2	Ordering Information Table on page 2: Removed part numbers ISL32614EMHZ-T and ISL32614EMHZ-T7A. Recommended Operating Conditions table on page 4: Removed the line referencing "M Suffix". Replaced "Product" section with "About Intersil" on page 10.
May 2, 2012	FN7906.1	Page 1, "Features" - changed "Specified for +125°C Operation" to "Specified for +125°C or Full Mil Temperature Operation". Also changed Figure 1 title. Page 2, added new part "ISL32614EMHZ-T" to the "Ordering Information". Page 4, changed "Y, Z (V _{CC} = 1.8V)" to "Y, Z (V _{CC} = 1.8V, Output Enabled)" and added "Y, Z (V _{CC} = 1.8V, Output Disabled)8V to +8V" under the "Absolute Maximum Rating". Also added "(F Suffix)" and "(M Suffix)55°C to +125°C" under the "Recommended Operating Conditions". Page 8, replaced Figure 7 and added -55°C curve to Figure 11 under the "Typical Performance Curves".
August 30, 2011	FN7906.0	Initial Release

About Intersil

Intersil Corporation is a leading provider of innovative power management and precision analog solutions. The company's products address some of the largest markets within the industrial and infrastructure, mobile computing and high-end consumer markets.

For the most updated datasheet, application notes, related documentation and related parts, please see the respective product information page found at www.intersil.com.

You may report errors or suggestions for improving this datasheet by visiting www.intersil.com/ask.

Reliability reports are also available from our website at www.intersil.com/support

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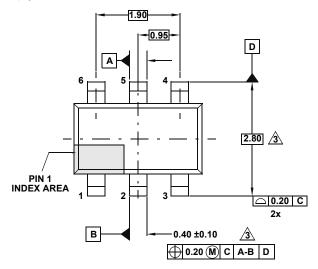
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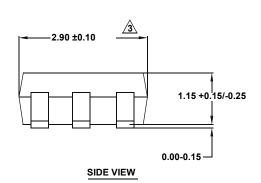
Package Outline Drawing

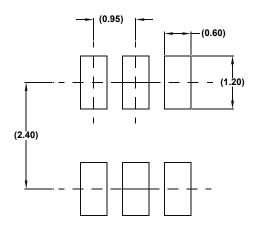
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6 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE Rev 4,2/10

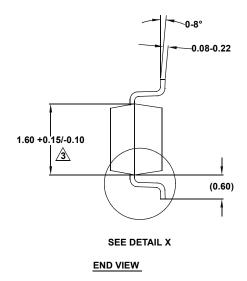


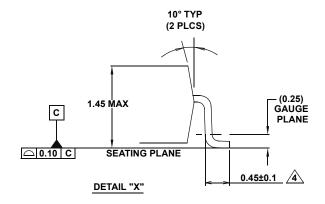
TOP VIEW





TYPICAL RECOMMENDED LAND PATTERN





NOTES:

- Dimensions are in millimeters.
 Dimensions in () for Reference Only.
- 2. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
- 3. Dimension is exclusive of mold flash, protrusions or gate burrs.
- 4. Foot length is measured at reference to gauge plane.
- 5. Package conforms to JEDEC MO-178AB.

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